Toshiba Memory Corporation Develops World’s First 3D Flash Memory with TSV Technology

Achieves high speed data input and output, low power consumption, large capacity

Düsseldorf, Germany, 11 July, 2017 - Toshiba Memory Corporation, the world leader in memory solutions, today announced development of the world’s first[1] BiCS FLASH™ three-dimensional (3D) flash memory[2] utilizing Through Silicon Via (TSV)[3] technology with 3-bit-per-cell (triple-level cell, TLC) technology. Shipments of prototypes for development purposes started in June, and product samples are scheduled for release in the second half of 2017. The prototype of this groundbreaking device will be showcased at the 2017 Flash Memory Summit in Santa Clara, California, United States, from August 7-10.

Devices fabricated with TSV technology have vertical electrodes and vias that pass through silicon dies to provide connections, an architecture that realizes high speed data input and output while reducing power consumption. Real-world performance has been proven previously, with the introduction of Toshiba’s 2D NAND Flash memory[4].

Combining a 48-layer 3D flash process and TSV technology has allowed Toshiba Memory
Corporation to successfully increase product programming bandwidth while achieving low power consumption. The power efficiency\textsuperscript{[5]} of a single package is approximately twice\textsuperscript{[6]} that of the same generation BiCS FLASH™ memory fabricated with wire-bonding technology. TSV BiCS FLASH™ also enables a 1-terabyte (TB) device with a 16-die stacked architecture in a single package.

Toshiba Memory Corporation will commercialize BiCS FLASH™ with TSV technology to provide an ideal solution in respect for storage applications requiring low latency, high bandwidth and high IOPS\textsuperscript{[7]}/Watt, including high-end enterprise SSDs.

General Specifications (Prototype)

<table>
<thead>
<tr>
<th>Package Type</th>
<th>NAND Dual x8 BGA-152</th>
</tr>
</thead>
<tbody>
<tr>
<td>Storage Capacity</td>
<td>512 GB</td>
</tr>
<tr>
<td></td>
<td>1 TB</td>
</tr>
<tr>
<td>Number of Stacks</td>
<td>8</td>
</tr>
<tr>
<td></td>
<td>16</td>
</tr>
<tr>
<td>External Dimension</td>
<td>W 14 mm</td>
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<tr>
<td></td>
<td>14 mm</td>
</tr>
<tr>
<td></td>
<td>D 18 mm</td>
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<tr>
<td></td>
<td>18 mm</td>
</tr>
<tr>
<td></td>
<td>H 1.35 mm</td>
</tr>
<tr>
<td></td>
<td>1.85 mm</td>
</tr>
<tr>
<td>Interface</td>
<td>Toggle DDR</td>
</tr>
<tr>
<td>Interface Max. Speed</td>
<td>1066Mbps</td>
</tr>
</tbody>
</table>

Notes:

[2] A structure stacking Flash memory cells vertically on a silicon substrate to realize significant density improvements over planar NAND Flash memory, where cells are formed on the silicon substrate.
[3] Through Silicon Via: the technology which has vertical electrodes and vias to pass through the silicon dies for connection in a single package.
[5] The rate of data transfer rate per power unit. (MB/s/W)
[7] Input Output per Second: The number of data inputs and outputs for processing through an I/O port per second. A higher value represents better performance.

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About Toshiba Electronics Europe

Toshiba Electronics Europe (TEE) is the European electronic components business of Toshiba Electronic Devices and Storage Corporation. TEE offers a broad IC and discrete product line including high-end memory, microcontrollers, ASICs and ASSPs for automotive, multimedia, industrial, telecoms and networking applications. The company also has a wide range of power semiconductor solutions as well as storage products including HDDs, SSDs, SD Cards and USB sticks.

TEE was formed in 1973 in Neuss, Germany, providing design, manufacturing, marketing and sales and now has headquarters in Düsseldorf, Germany, with branch offices in France, Italy, Spain, Sweden and the United Kingdom. TEE employs approximately 300 people in Europe. Company president is Mr. Akira Morinaga.

For more company information visit TEE’s web site at www.toshiba.semicon-storage.com.

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